NSN 5961-01-247-1382

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Inclosure Material:

Metal

Overall Length:

1.550 inches

Overall Height:

0.300 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

700.0 collector-to-emitter, with voltage between base and emitter and 600.0 collector-to-emitter, substaining voltage, base open-circuited and 8.0 emitter to base, rms

Current Rating Per Characteristic:

10.00 amperes source cutoff current and 7.00 amperes source cutoff current

Power Rating Per Characteristic:

175.0 watts small-signal input power, common-collector absolute

Transfer Ratio:

10.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Terminal Type And Quantity:

2 tab, solder lug and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0